VS-80EBU02HF4

Vishay Semiconductors

Ultrafast Soft Recovery Diode, 80 A FRED Pt[®]



PowerTab[®]

PRODUCT SUMMARY				
Package	PowerTab [®]			
I _{F(AV)}	80 A			
V _R	200 V			
V _F at I _F	0.77 V			
t _{rr} (typ.) See recovery table				
Т _J max. 175 °С				
Diode variation	Single die			

FEATURES

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- · Screw mounting only
- AEC-Q101 gualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V _R		200	V
Continuous forward current	I _{F(AV)}	T _C = 131 °C	80	
Single pulse forward current	I _{FSM}	T _C = 25 °C	800	А
Maximum repetitive forward current	I _{FRM}	Square wave, 20 kHz	160	
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	DL TEST CONDITIONS		TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _r	I _R = 50 μA	200	-	-	
Forward voltage	¥-	I _F = 80 A	-	0.94	1.10	V
Forward voltage V _F	٧F	I _F = 80 A, T _J = 175 °C	-	0.77	0.88	
Reverse leakage current I _R		$V_{R} = V_{R}$ rated	-	-	50	μA
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	2	mA
Junction capacitance	CT	V _R = 200 V - 89 -		-	pF	
Series inductance	Ls	Measured lead to lead 5 mm from package body - 3.5 -		nH		

Revision: 16-Jun-15



RoHS

COMPLIANT





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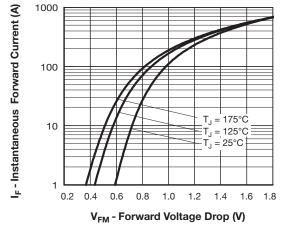
DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time t _{rr}	+	T _J = 25 °C		-	40	-	ns
	۲r	T _J = 125 °C		-	75	-	
Peak recovery current I _{RRM}		T _J = 25 °C	I _F = 80 A V _B = 160 V	-	4.0	-	А
	T _J = 125 °C	v _R = 160 v dI _F /dt = 200 A/µs	-	8.8	-	~	
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	75	-	
	Q _{rr}	T _J = 125 °C		-	310	-	nC

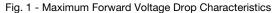
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R _{thJC}		-	-	0.5	°C/W
Thermal resistance, junction to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	0/11
Weight			-	-	5.02	g
weight			-	0.18	-	oz.
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)
Marking device		Case style PowerTab®		80EB	U02H	

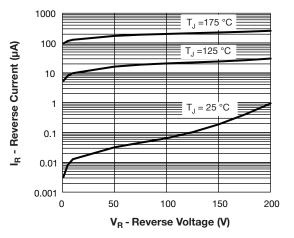


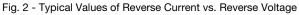
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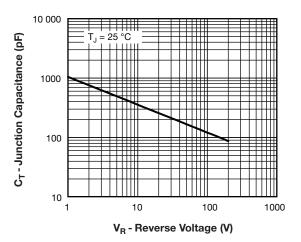
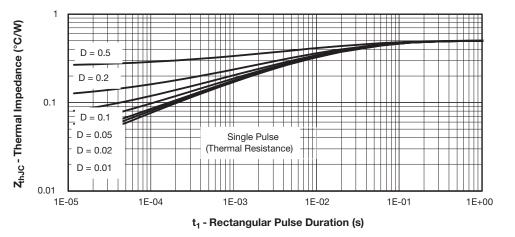
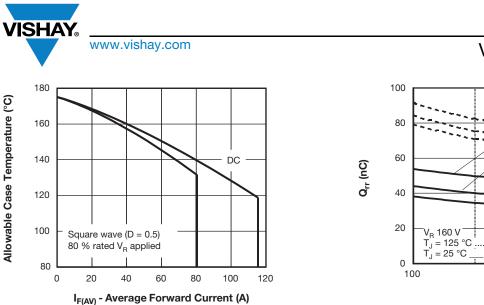
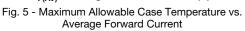


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage









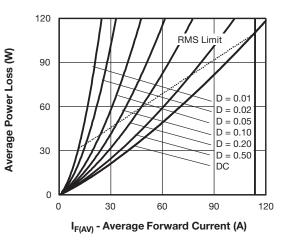


Fig. 6 - Forward Power Loss Characteristics



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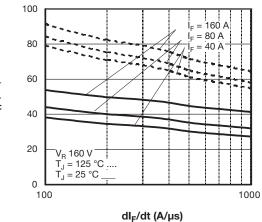


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

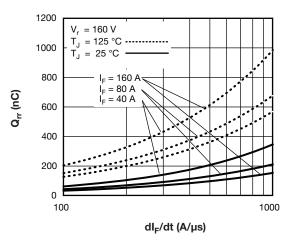


Fig. 8 - Typical Stored Charge vs. dl_F/dt

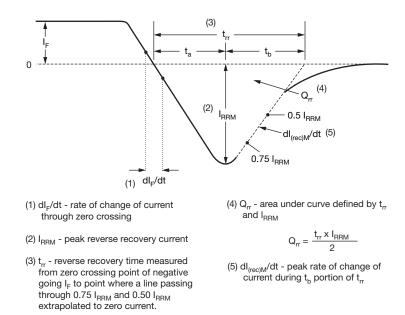


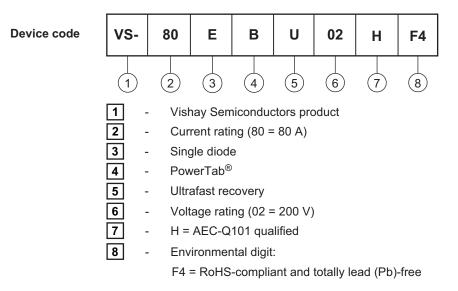
Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)							
PREFERRED P/N	EFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-80EBU02HF4	25	375	Antistatic plastic tube				

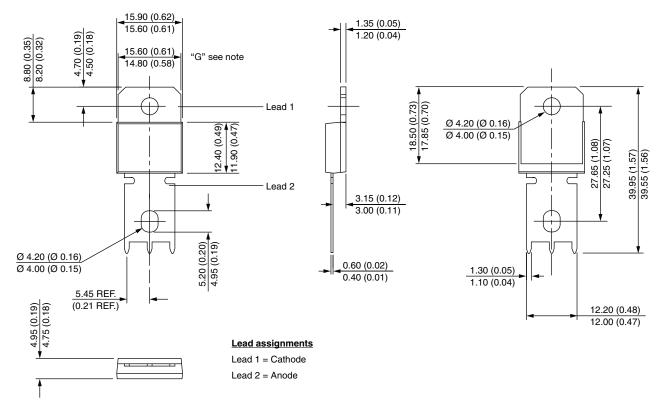
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95240				
Part marking information	www.vishay.com/doc?95467			
Application note	www.vishay.com/doc?95179			



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DIMENSIONS in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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